ECE 518  **Adv Semiconductor Nanotech**  credit: 4 hours.
Semiconductor nanotechnology from the formation and characterization of low-dimensional structures to device applications. Compound semiconductors, epitaxial growth, quantum dots, nanowires, membranes, strain effect, quantum confinement, surface states, 3D transistors, nanolasers, multijunction tandem solar cells, and nanowire thermoelectrics. Handouts are supplemented with papers from the research literature. Critical literature review assignments, research proposals in National Science Foundation format, and oral presentations are required. Prerequisites: ECE 340, ECE 444, and ECE 481.

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Restricted to Graduate - Urbana-Champaign.